



SANYO Semiconductors

DATA SHEET

BXL4001

N-Channel Silicon MOSFET — General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- Motor drive.
- Avalanche resistance guarantee.
- 10V drive.

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DS}		75	V
Gate-to-Source Voltage	V_{GS}		± 20	V
Drain Current (DC)	I_D		85	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	340	A
Allowable Power Dissipation	P_D		1.75	W
		$T_c=25^\circ\text{C}$	75	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$
Avalanche Energy (Single Pulse) *1	E_{AS}		211	mJ
Avalanche Current *2	I_{AV}		51	A

Note : *1 $V_{DD}=30\text{V}$, $L=100\mu\text{H}$, $I_{AV}=51\text{A}$

*2 $L \leq 100\mu\text{H}$, Single pulse

Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1\text{mA}$, $V_{GS}=0\text{V}$	75			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=75\text{V}$, $V_{GS}=0\text{V}$			1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16\text{V}$, $V_{DS}=0\text{V}$			± 10	μA

Marking : XL4001

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BXL4001

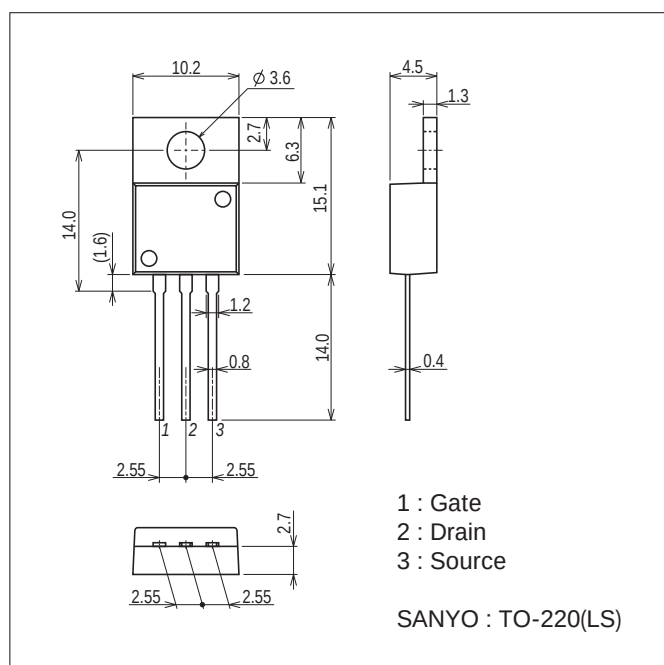
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V, I_D=1mA$	2		4	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V, I_D=43A$		75		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)}$	$I_D=43A, V_{GS}=10V$		9.0	12.4	$m\Omega$
Input Capacitance	C_{iss}	$V_{DS}=20V, f=1MHz$		6700		pF
Output Capacitance	C_{oss}	$V_{DS}=20V, f=1MHz$		590		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=20V, f=1MHz$		440		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		75		ns
Rise Time	t_r	See specified Test Circuit.		340		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		260		ns
Fall Time	t_f	See specified Test Circuit.		170		ns
Total Gate Charge	Q_g	$V_{DS}=30V, V_{GS}=10V, I_D=85A$		115		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS}=30V, V_{GS}=10V, I_D=85A$		37		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS}=30V, V_{GS}=10V, I_D=85A$		30		nC
Diode Forward Voltage	V_{SD}	$I_S=85A, V_{GS}=0V$		1.0	1.5	V

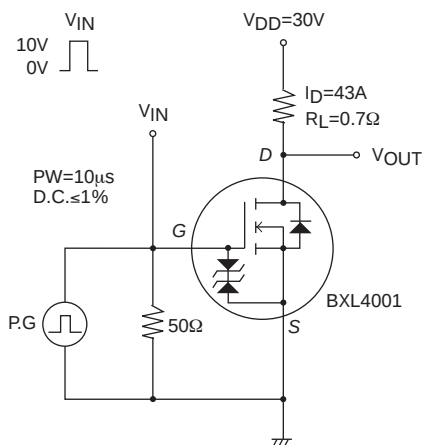
Package Dimensions

unit : mm (typ)

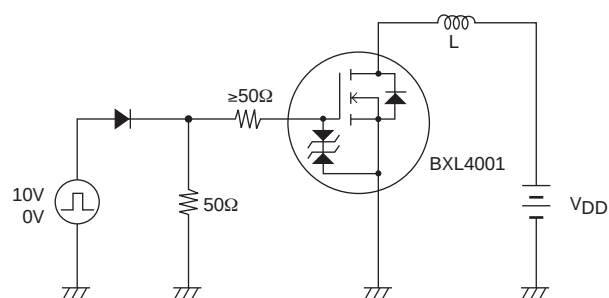
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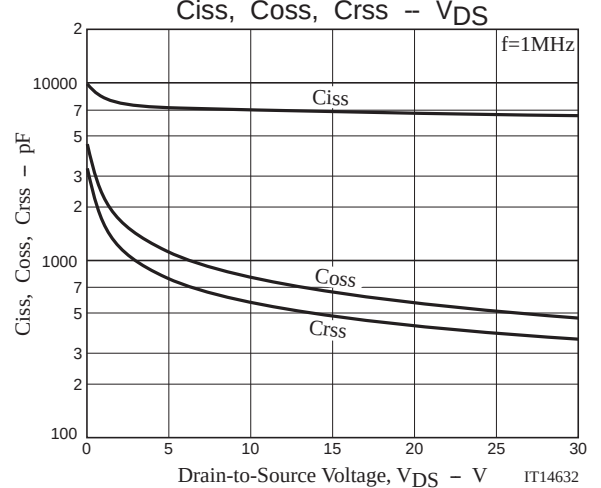
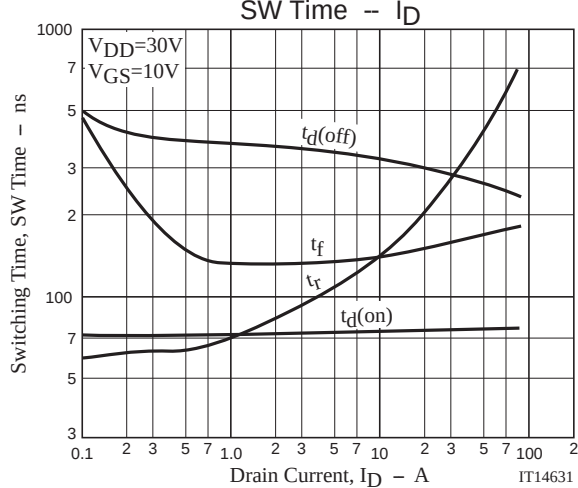
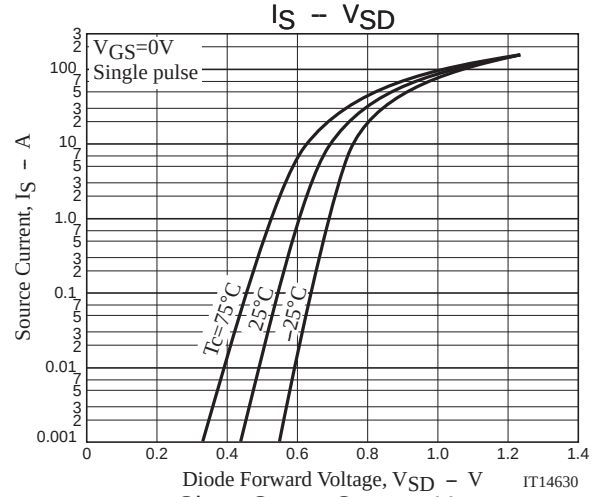
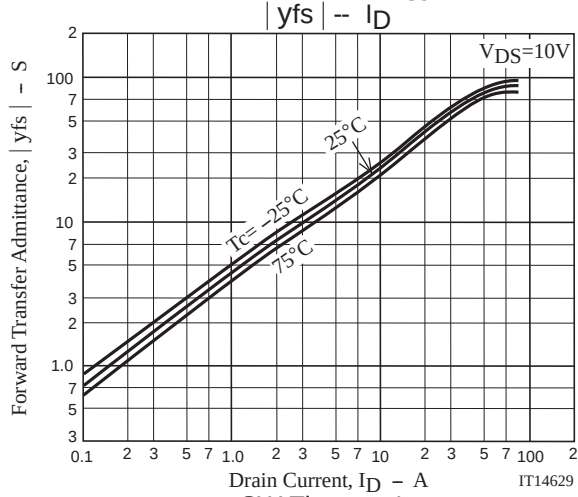
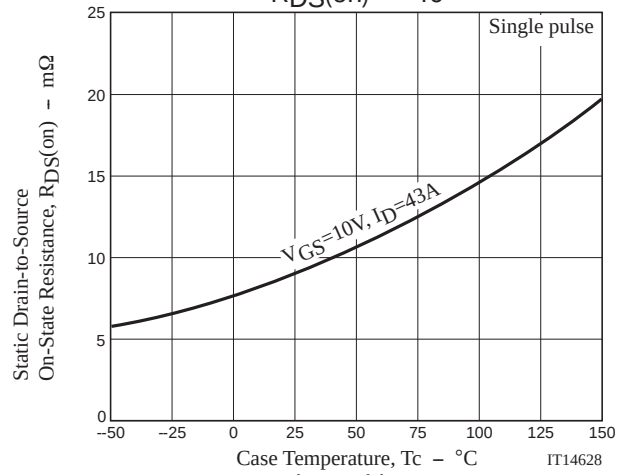
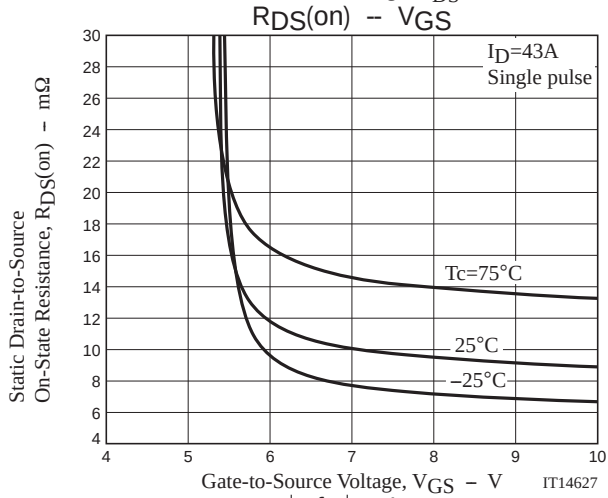
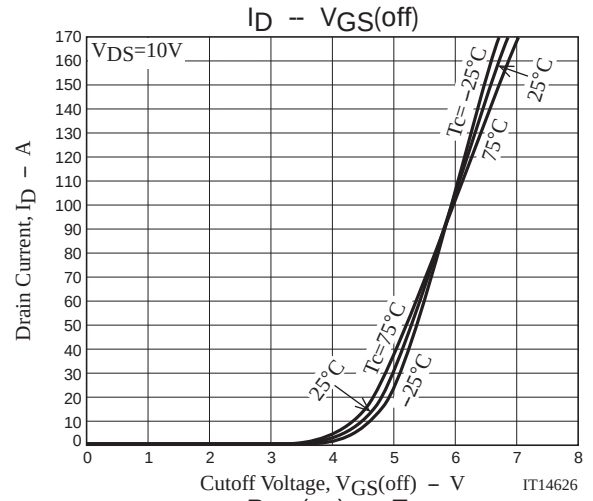
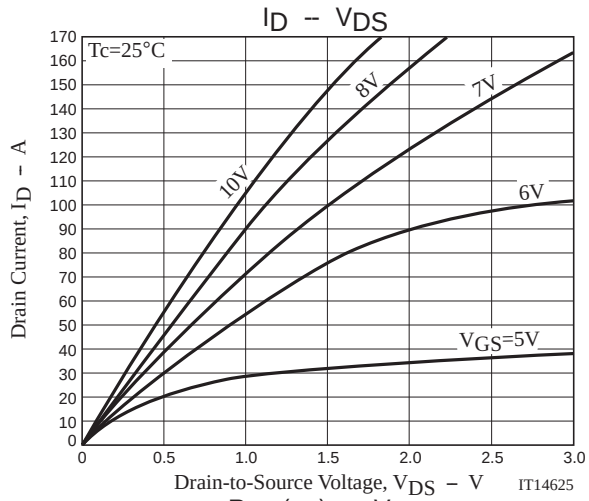


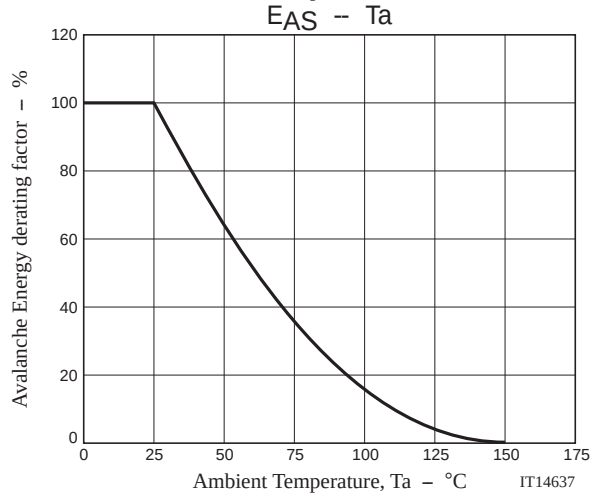
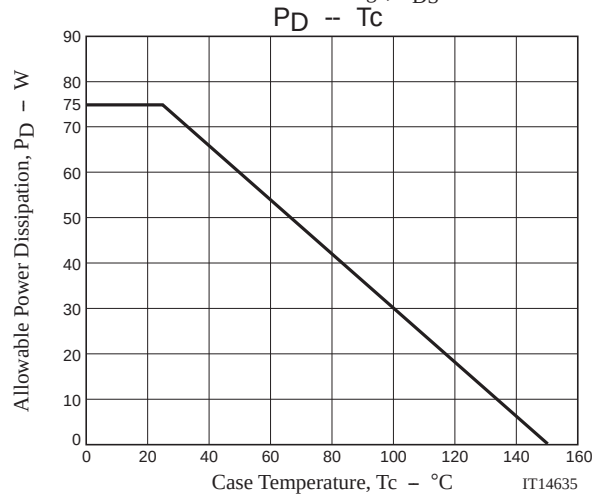
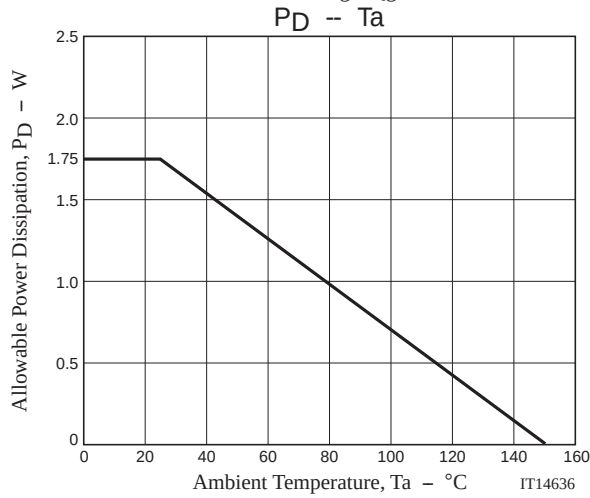
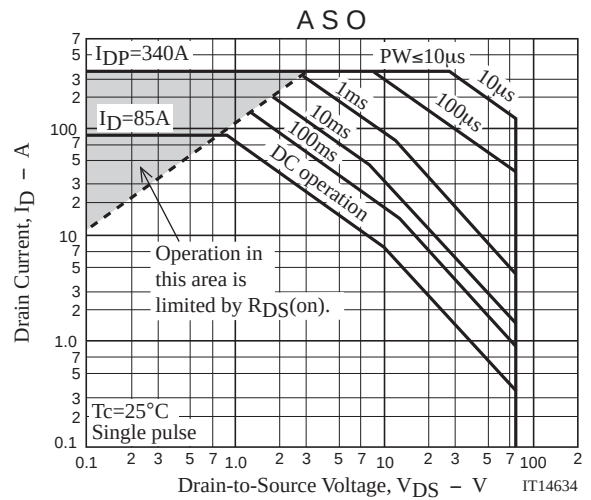
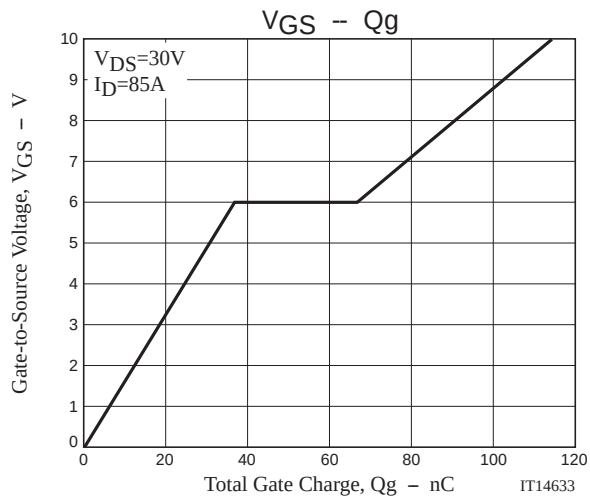
Switching Time Test Circuit



Avalanche Resistance Test Circuit







Note on usage : Since the BXL4001 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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